MOSFET – Power, Single, N-Channel, SOT-23

20 V, 3.2 A

Features

- Leading Planar Technology for Low Gate Charge / Fast Switching
- 2.5 V Rated for Low Voltage Gate Drive
- SOT-23 Surface Mount for Small Footprint
- NVR Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb-Free and are RoHS Compliant

Applications

- Load/Power Switch for Portables
- Load/Power Switch for Computing
- DC-DC Conversion

MAXIMUM RATINGS (T_J= 25°C unless otherwise stated)

Paramo	Symbol	Value	Unit		
Drain-to-Source Voltage			V _{DSS}	20	V
Gate-to-Source Voltage			V _{GS}	±12	V
Continuous Drain	Steady T _A = 25°C		I _D	3.2	Α
Current (Note 1)	State	State T _A = 85°C		2.4	Α
Steady State Power Dissipation (Note 1)	Stea	dy State	P _D	1.25	W
Pulsed Drain Current	t _p =	= 10 μs	I _{DM}	10.0	Α
Operating Junction and Storage Temperature			T _J , T _{stg}	–55 to 150	°C
Continuous Source Current (Body Diode)			Is	1.6	Α
Lead Temperature for Solo (1/8" from case for 10	TL	260	°C		

THERMAL RESISTANCE RATINGS

Parameter	Symbol	Max	Unit
Junction-to-Ambient (Note 1)	$R_{\theta JA}$	100	°C/W
Junction-to-Ambient (Note 2)	$R_{\theta JA}$	300	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

- 1. Surface-mounted on FR4 board using 1 in sq pad size (Cu area = 1.127 in sq [1 oz] including traces).
- 2. Surface-mounted on FR4 board using the minimum recommended pad size.

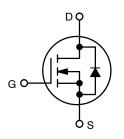


ON Semiconductor®

www.onsemi.com

V _{(BR)DSS}	R _{DS(on)} Typ	I _D Max (Note 1)	
20 V	70 mΩ @ 4.5 V	3.6 A	
	88 mΩ @ 2.5 V	3.1 A	

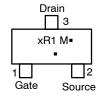
N-Channel



MARKING DIAGRAM & PIN ASSIGNMENT



SOT-23 **CASE 318** STYLE 21



TR1 = Device Code for NTR4501N VR1 = Device Code for NVR4501N

= Date Code* = Pb-Free Package

(Note: Microdot may be in either location)

*Date Code orientation and/or overbar may vary depending upon manufacturing location.

ORDERING INFORMATION

Device	Package	Shipping†
NTR4501NT1G	SOT-23 (Pb-Free)	3000 / Tape & Reel
NVR4501NT1G	SOT-23 (Pb-Free)	3000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

Electrical Characteristics ($T_J = 25^{\circ}C$ unless otherwise specified)

Symbol	Test Condition		Min	Тур	Max	Units
•		•		•		
V _{(BR)DSS}	$V_{GS} = 0 \text{ V}, I_D = 250 \mu\text{A}$		20	24.5		V
V _{(BR)DSS} /T _J				22		mV/°C
I _{DSS}	V _{GS} = 0 V	T _J = 25°C			1.5	μΑ
	V _{DS} = 16 V	T _J = 85°C			10	μΑ
I _{GSS}	$V_{DS} = 0 V, V_{C}$	_{SS} = ±12 V			±100	nA
V _{GS(TH)}	V _{GS} = V _{DS} , I _E	ο = 250 μΑ	0.65		1.2	V
V _{GS(TH)} /T _J				-2.3		mV/°C
	V _{GS} = 4.5 V, I _D = 3.6 A V _{GS} = 2.5 V, I _D = 3.1 A			70	80	
R _{DS(on)}				88	105	mΩ
9FS	V _{DS} = 5.0 V, I _D = 3.6 A			9		S
C _{iss}	V _{GS} = 0 V, f = 1.0 MHz, V _{DS} = 10 V			200		pF
C _{oss}				80		
C _{rss}				50		
Q _{G(TOT)}				2.4	6.0	nC
Q_{GS}	$V_{GS} = 4.5 \text{ V}, \text{ V}$	′ _{DS} = 10 V, 6 A		0.5		
Q_{GD}	ID - 0.0 A			0.6		1
t _{d(on)}				6.5	13	
t _r	V _{GS} = 4.5 V, V	_{'ns} = 10 V,		12	24	ns
t _{d(off)}	$I_D = 3.6 A, R$	$_{\rm G}$ = 6.0 Ω		12	24	
t _f				3	6	7
S						
V_{SD}	V _{GS} = 0 V, I _S	_{SD} = 1.6 A		0.8	1.2	V
t _{RR}	$V_{GS} = 0 \text{ V},$ $d_{IS}/d_t = 100 \text{ A}/\mu\text{s},$ $I_S = 1.6 \text{ A}$			7.1		
t _a				5		ns
t _b				1.9		
	Symbol V(BR)DSS V(BR)DSS/TJ IDSS V(BR)DSS/TJ IDSS V(BR)DSS/TJ V(BR)DSS/TJ V(BR)DSS/TJ V(BR)DSS/TJ V(BR)DSS V(BR)DSS/TJ V(BR)DS/TJ V(BR)DS/TJ V(BR)DS/TJ V(BR)DS/TJ V	V(BR)DSS	$ \begin{array}{ c c c } \hline \textbf{Symbol} & \textbf{Test Condition} \\ \hline \hline & V_{(BR)DSS} & V_{GS} = 0 \text{ V}, I_{D} = 250 \mu\text{A} \\ \hline & V_{(BR)DSS}/T_{J} & \\ \hline & I_{DSS} & V_{GS} = 0 \text{ V} & T_{J} = 25^{\circ}\text{C} \\ \hline & V_{DS} = 16 \text{ V} & T_{J} = 85^{\circ}\text{C} \\ \hline & V_{DS} = 16 \text{ V} & T_{J} = 85^{\circ}\text{C} \\ \hline & V_{GS}(TH) & V_{GS} = V_{DS}, I_{D} = 250 \mu\text{A} \\ \hline & V_{GS}(TH)/T_{J} & \\ \hline & V_{GS}(TH)/T_{J} & \\ \hline & V_{GS} = 4.5 \text{ V}, I_{D} = 3.6 \text{ A} \\ \hline & V_{GS} = 2.5 \text{ V}, I_{D} = 3.6 \text{ A} \\ \hline & V_{GS} = 2.5 \text{ V}, I_{D} = 3.6 \text{ A} \\ \hline & V_{DS} = 5.0 \text{ V}, I_{D} = 3.6 \text{ A} \\ \hline & V_{GS} = 0 \text{ V}, f = 1.0 \text{ MHz}, \\ \hline & V_{GS} = 4.5 \text{ V}, V_{DS} = 10 \text{ V}, \\ \hline & I_{D} = 3.6 \text{ A} & \\ \hline & V_{GS} = 4.5 \text{ V}, V_{DS} = 10 \text{ V}, \\ \hline & I_{D} = 3.6 \text{ A}, R_{G} = 6.0 \Omega \\ \hline & V_{SD} & V_{GS} = 0 \text{ V}, I_{SD} = 1.6 \text{ A} \\ \hline & V_{GS} = 0 \text{ V}, \\ \hline & I_{B} & I_{A} & \\ \hline & V_{GS} = 0 \text{ V}, \\ \hline & I_{B} & I_{OS} = 0 \text{ V}, \\ \hline & I_{CS} = 0$	$ \begin{array}{ c c c c } \hline \textbf{Symbol} & \textbf{Test Condition} & \textbf{Min} \\ \hline \hline & V_{(BR)DSS} & V_{GS} = 0 \text{ V}, I_D = 250 \mu\text{A} & 20 \\ \hline & V_{(BR)DSS}/T_J & & & & \\ \hline & I_{DSS} & V_{GS} = 0 \text{ V} & T_J = 25^{\circ}\text{C} \\ \hline & V_{DS} = 16 \text{ V} & T_J = 85^{\circ}\text{C} \\ \hline & I_{GSS} & V_{DS} = 0 \text{ V}, V_{GS} = \pm 12 \text{ V} \\ \hline & V_{GS(TH)} & V_{GS} = V_{DS}, I_D = 250 \mu\text{A} & 0.65 \\ \hline & V_{GS(TH)}/T_J & & & \\ \hline & V_{GS} = 4.5 \text{ V}, I_D = 3.6 \text{ A} \\ \hline & V_{GS} = 2.5 \text{ V}, I_D = 3.6 \text{ A} \\ \hline & V_{DS} = 5.0 \text{ V}, I_D = 3.6 \text{ A} \\ \hline & V_{DS} = 5.0 \text{ V}, I_D = 3.6 \text{ A} \\ \hline & C_{ISS} & V_{GS} = 0 \text{ V}, f = 1.0 \text{ MHz}, \\ \hline & C_{CRS} & V_{GS} = 0 \text{ V}, V_{DS} = 10 \text{ V}, \\ \hline & I_D = 3.6 \text{ A} \\ \hline & V_{GS} = 4.5 \text{ V}, V_{DS} = 10 \text{ V}, \\ \hline & I_D = 3.6 \text{ A}, R_G = 6.0 \Omega \\ \hline & V_{SD} & V_{GS} = 0 \text{ V}, I_{SD} = 1.6 \text{ A} \\ \hline & t_{RR} & V_{GS} = 0 \text{ V}, \\ \hline & I_D = 4.6 \text{ A} \\ \hline & V_{GS} = 0 \text{ V}, \\ \hline & V_$	$ \begin{array}{ c c c c c } \hline \textbf{Symbol} & \textbf{Test Condition} & \textbf{Min} & \textbf{Typ} \\ \hline \hline & V_{(BR)DSS} & V_{GS} = 0 \text{ V}, I_D = 250 \mu\text{A} & 20 & 24.5 \\ \hline & V_{(BR)DSS}/T_J & & 22 & \\ \hline & I_{DSS} & V_{GS} = 0 \text{ V} & T_J = 25^{\circ}\text{C} \\ \hline & V_{DS} = 16 \text{ V} & T_J = 85^{\circ}\text{C} & \\ \hline & I_{GSS} & V_{DS} = 0 \text{ V}, V_{GS} = \pm 12 \text{ V} \\ \hline \hline & V_{GS(TH)} & V_{GS} = V_{DS}, I_D = 250 \mu\text{A} & 0.65 & \\ \hline & V_{GS(TH)}/T_J & & -2.3 & \\ \hline & V_{GS(TH)}/T_J & & -2.3 & \\ \hline & V_{GS}(TH)/T_J & & -2.3 & \\ \hline & V_{GS} = 4.5 \text{ V}, I_D = 3.6 \text{ A} & 70 & \\ \hline & V_{GS} = 2.5 \text{ V}, I_D = 3.6 \text{ A} & 9 & \\ \hline & & & & & & & & & & & & \\ \hline & C_{ISS} & & & & & & & & & & \\ \hline & C_{ISS} & & & & & & & & & & & \\ \hline & C_{ISS} & & & & & & & & & & & \\ \hline & C_{ISS} & & & & & & & & & & & & \\ \hline & C_{ISS} & & & & & & & & & & & & \\ \hline & C_{ISS} & & & & & & & & & & & & \\ \hline & C_{ISS} & & & & & & & & & & & & \\ \hline & C_{ISS} & & & & & & & & & & & & \\ \hline & C_{ISS} & & & & & & & & & & & & \\ \hline & C_{ISS} & & & & & & & & & & & & & \\ \hline & C_{ISS} & & & & & & & & & & & & \\ \hline & C_{ISS} & & & & & & & & & & & & & \\ \hline & C_{ISS} & & & & & & & & & & & & & & \\ \hline & C_{ISS} & & & 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& & & & & & & \\ \hline & C_{ISS$	$ \begin{array}{ c c c c c c } \hline \textbf{Symbol} & \textbf{Test Condition} & \textbf{Min} & \textbf{Typ} & \textbf{Max} \\ \hline \hline & V_{(BR)DSS} & V_{GS} = 0 \text{ V, } I_D = 250 \ \mu\text{A} & 20 & 24.5 \\ \hline & V_{(BR)DSS}/T_J & 22 & \\ \hline & I_{DSS} & V_{GS} = 0 \text{ V} & T_J = 25^{\circ}\text{C} & 1.5 \\ \hline & V_{DS} = 16 \text{ V} & T_J = 85^{\circ}\text{C} & 10 \\ \hline & I_{GSS} & V_{DS} = 0 \text{ V, } V_{GS} = \pm 12 \text{ V} & \pm 100 \\ \hline & V_{GS(TH)} & V_{GS} = V_{DS}, I_D = 250 \ \mu\text{A} & 0.65 & 1.2 \\ \hline & V_{GS(TH)}/T_J & -2.3 & & \\ \hline & V_{GS(TH)}/T_J & -2.3 & & \\ \hline & V_{GS} = 4.5 \text{ V, } I_D = 3.6 \text{ A} & 70 & 80 \\ \hline & V_{GS} = 2.5 \text{ V, } I_D = 3.6 \text{ A} & 9 & \\ \hline & V_{GS} = 2.5 \text{ V, } I_D = 3.6 \text{ A} & 9 & \\ \hline & C_{ISS} & V_{GS} = 5.0 \text{ V, } I_D = 3.6 \text{ A} & 9 & \\ \hline & C_{ISS} & V_{GS} = 10 \text{ V} & 2.4 & 6.0 \\ \hline & C_{GS} & V_{GS} = 4.5 \text{ V, } V_{DS} = 10 \text{ V, } & 2.4 & 6.0 \\ \hline & Q_{G} & 0.6 & & \\ \hline & t_d(on) & I_D = 3.6 \text{ A, } R_G = 6.0 \ \Omega & 12 & 24 \\ \hline & t_f & 3 & 6 \\ \hline & S & & V_{SD} & V_{GS} = 0 \text{ V, } I_{SD} = 1.6 \text{ A} & 0.8 & 1.2 \\ \hline & t_{RR} & V_{GS} = 0 \text{ V, } I_{SD} = 1.6 \text{ A} & 0.8 & 1.2 \\ \hline & t_{RR} & V_{GS} = 0 \text{ V, } I_{SD} = 1.6 \text{ A} & 0.8 & 1.2 \\ \hline & t_{RR} & V_{GS} = 0 \text{ V, } I_{SD} = 1.0 \text{ A/µs,} & 5 & \\ \hline & t_{RR} & V_{GS} = 0 \text{ V, } I_{SD} = 1.6 \text{ A} & 0.8 & 1.2 \\ \hline & t_{RR} & V_{GS} = 0 \text{ V, } I_{SD} = 1.6 \text{ A} & 0.8 & 1.2 \\ \hline & t_{RR} & V_{GS} = 0 \text{ V, } I_{SD} = 1.6 \text{ A} & 0.8 & 1.2 \\ \hline & t_{RR} & V_{GS} = 0 \text{ V, } I_{SD} = 1.0 \text{ A/µs,} & 5 & \\ \hline & t_{RR} & V_{GS} = 0 \text{ V, } I_{SD} = 1.0 \text{ A/µs,} & 5 & \\ \hline & t_{RR} & V_{GS} = 0 \text{ V, } I_{SD} = 1.0 \text{ A/µs,} & 5 & \\ \hline & t_{RR} & V_{GS} = 0 \text{ V, } I_{SD} = 1.0 \text{ A/µs,} & 5 & \\ \hline & t_{RR} & V_{GS} = 0 \text{ V, } I_{SD} = 1.0 \text{ A/µs,} & 5 & \\ \hline & t_{RR} & V_{GS} = 0 \text{ V, } I_{SD} = 1.0 \text{ A/µs,} & 5 & \\ \hline & t_{RR} & V_{GS} = 0 \text{ V, } I_{SD} = 1.0 \text{ A/µs,} & 5 & \\ \hline & t_{RR} & V_{GS} = 0 \text{ V, } I_{SD} = 1.0 \text{ A/µs,} & 5 & \\ \hline & t_{RR} & V_{GS} = 0 \text{ V, } I_{SD} = 1.0 \text{ A/µs,} & 5 & \\ \hline & t_{RR} & V_{GS} = 0 \text{ V, } I_{SD} = 1.0 \text{ A/µs,} & 5 & \\ \hline & t_{RR} & V_{GS} = 0 \text{ V, } I_{SD} = 0 \text{ V,} & 5 $

Pulse Test: Pulse width ≤ 300 μs, duty cycle ≤ 2%.
 Switching characteristics are independent of operating junction temperatures.

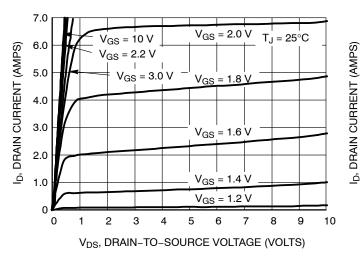
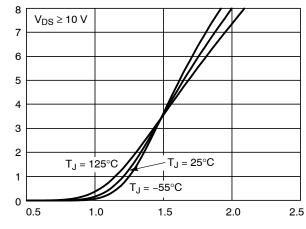


Figure 1. On-Region Characteristics



V_{GS}, GATE-TO-SOURCE VOLTAGE (VOLTS)

Figure 2. Transfer Characteristics

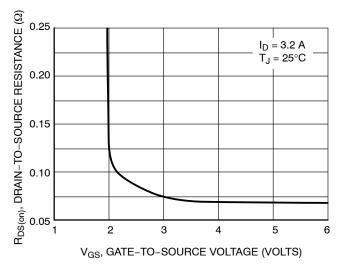


Figure 3. On-Resistance versus Gate-to-Source Voltage

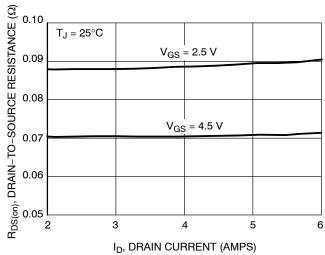


Figure 4. On-Resistance versus Drain Current and Gate Voltage

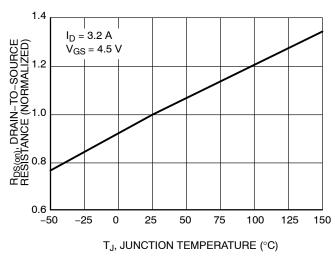


Figure 5. On–Resistance Variation with Temperature

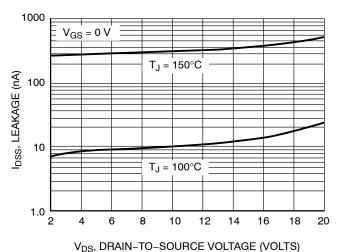


Figure 6. Drain-to-Source Leakage Current versus Voltage

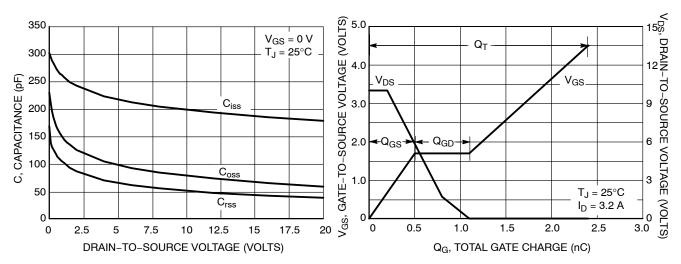


Figure 7. Capacitance Variation

Figure 8. Gate-to-Source and Drain-to-Source Voltage versus Total Charge

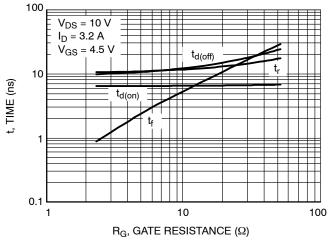


Figure 9. Resistive Switching Time Variation versus Gate Resistance

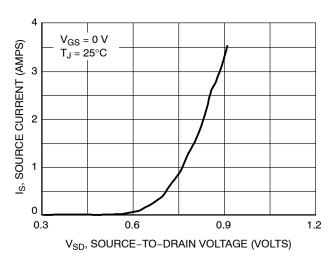


Figure 10. Diode Forward Voltage versus

Current

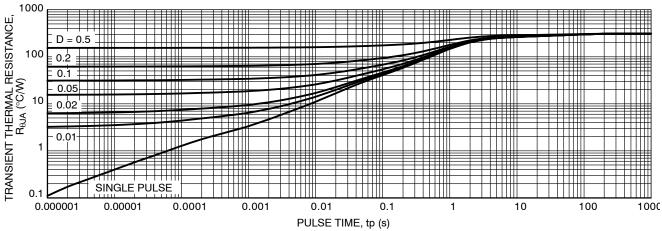


Figure 11. Thermal Response



SOT-23 (TO-236) CASE 318-08 **ISSUE AS**

DATE 30 JAN 2018

SCALE 4:1 D - 3X b **TOP VIEW**







RECOMMENDED SOLDERING FOOTPRINT



DIMENSIONS: MILLIMETERS

3. ANODE

NOTES:

- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
 2. CONTROLLING DIMENSION: MILLIMETERS.
 3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH.
 MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF THE BASE MATERIAL
- 4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

	MILLIMETERS				INCHES	
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.89	1.00	1.11	0.035	0.039	0.044
A1	0.01	0.06	0.10	0.000	0.002	0.004
b	0.37	0.44	0.50	0.015	0.017	0.020
С	0.08	0.14	0.20	0.003	0.006	0.008
D	2.80	2.90	3.04	0.110	0.114	0.120
E	1.20	1.30	1.40	0.047	0.051	0.055
е	1.78	1.90	2.04	0.070	0.075	0.080
L	0.30	0.43	0.55	0.012	0.017	0.022
L1	0.35	0.54	0.69	0.014	0.021	0.027
HE	2.10	2.40	2.64	0.083	0.094	0.104
Т	O٥		10°	O۰		10°

GENERIC MARKING DIAGRAM*



XXX = Specific Device Code

= Date Code

= Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ■", may or may not be present.

STYLE 1 THRU 5: CANCELLED	STYLE 6: PIN 1. BASE 2. EMITTER 3. COLLECTOR	STYLE 7: PIN 1. EMITTER 2. BASE 3. COLLECTOR	STYLE 8: PIN 1. ANODE 2. NO CONNECTION 3. CATHODE	ı	
STYLE 9:	STYLE 10:	STYLE 11: PIN 1. ANODE 2. CATHODE 3. CATHODE-ANODE	STYLE 12:	STYLE 13:	STYLE 14:
PIN 1. ANODE	PIN 1. DRAIN		PIN 1. CATHODE	PIN 1. SOURCE	PIN 1. CATHODE
2. ANODE	2. SOURCE		2. CATHODE	2. DRAIN	2. GATE
3. CATHODE	3. GATE		3. ANODE	3. GATE	3. ANODE
STYLE 15:	STYLE 16:	STYLE 17: PIN 1. NO CONNECTION 2. ANODE 3. CATHODE	STYLE 18:	STYLE 19:	STYLE 20:
PIN 1. GATE	PIN 1. ANODE		PIN 1. NO CONNECTION	I PIN 1. CATHODE	PIN 1. CATHODE
2. CATHODE	2. CATHODE		2. CATHODE	2. ANODE	2. ANODE
3. ANODE	3. CATHODE		3. ANODE	3. CATHODE-ANODE	3. GATE
STYLE 21:	STYLE 22:	STYLE 23:	STYLE 24:	STYLE 25:	STYLE 26:
PIN 1. GATE	PIN 1. RETURN	PIN 1. ANODE	PIN 1. GATE	PIN 1. ANODE	PIN 1. CATHODE
2. SOURCE	2. OUTPUT	2. ANODE	2. DRAIN	2. CATHODE	2. ANODE
3. DRAIN	3. INPUT	3. CATHODE	3. SOURCE	3. GATE	3. NO CONNECTION
STYLE 27: PIN 1. CATHODE 2. CATHODE	STYLE 28: PIN 1. ANODE 2. ANODE				

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DESCRIPTION:	SOT-23 (TO-236)		PAGE 1 OF 1	

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3. CATHODE

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